



# Low Voltage, Dual DPDT in miniQFN16

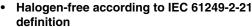
### DESCRIPTION

The DG2599 is a  $C_{MOS}$  Dual DPDT (Dual Double Pole Double Throw) analog switch that operates over a wide voltage range of 1.65 V to 5 V. It is optimized for portable applications switching audio, SIM card signals, and other low power signals.

The DG2599 features low ON resistance of 2.8  $\Omega$  at 3 V power supply, fast switching speed, and low power consumption even when control logic signals are below V+ power supply voltage. The well matched dual DPDT switches conduct signals equally in both directions. The DG2599 is designed to guarantee break before make switching.

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with lead (Pb)-free device terminations. DG2599 are offered in a miniQFN package. The miniQFN package has a nickel palladium- gold device termination and is represented by the lead (Pb)-free "-E4" suffix. The nickel-palladium-gold device terminations meet all JEDEC standards for reflow and MSL ratings.

### **FEATURES**





- Low on-resistance 2.8  $\Omega$  at V+ = 3 V
- Power off protection on COM1 and COM2 pins
- Latch up current great than 300 mA per JESD78
- Compliant to RoHS Directive 2002/95/EC

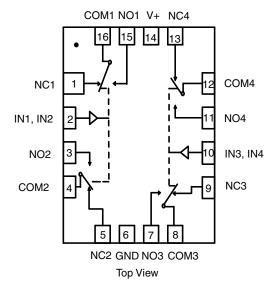


HALOGEN FREE

### **APPLICATIONS**

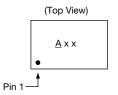
- · Cellular phones
- · PMPs and PDAs
- Modems and peripherals
- Computers and ebooks
- Tablet devices
- Displays and gaming
- STB

ORDERING INFORMATION					
Part Number	Package				
DG2599DN-T1-GE4	miniQFN16 1.8 mm x 2.6 mm				



TRUTH TABLE (DG2599)					
Logic	gic NC1, 2, 3 and 4 NO 1, 2, 3 ar				
0	ON	OFF			
1	OFF	ON			

Device Marking: A xx xx = Date/Lot Traceability Code



Note: Pin 1 has long lead



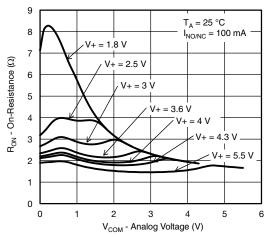
<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C, unless otherwise noted)					
Parameter		Symbol	Limit	Unit	
Reference to GND	V+		- 0.3 to 5	V	
Reference to GND	IN, COM, NC, NO <sup>a</sup>		- 0.3 to (V+ + 0.3)		
Current (any terminal except NO, NC or		30			
Continuous Current (NO, NC, or COM)		± 300	mA		
Peak Current (pulsed at 1 ms, 10 % duty		± 500			
Storage Temperature (D Suffix)			- 65 to 150		
Package Solder Reflow Conditions <sup>d</sup>	miniQFN16		250	°C	
Power Dissipation (Packages) <sup>b</sup>	miniQFN16 <sup>c</sup>		525	mW	

- a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 6.6 mW/°C above 70 °C.
- d. Manual soldering with iron is not recommended for leadless components. The miniQFN-16 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

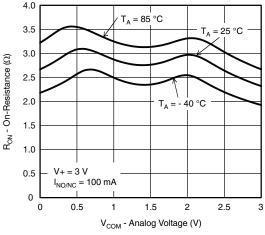
Parameter	Test Conditions	Temp.	Min.	Тур.	Max.	Unit	
Power Supply and Signal							
V+ Supply Voltage		Full	1.65		5	V	
V+ Supply Current	V <sub>IN</sub> = 0 or V+	Full		0.001	2	μΑ	
Analog Signal Range		Full	0		V+	V	
Switch On-Resistance and Leakag	е						
Drain-Source On-Resistance	V+ = 3 V, I <sub>NO/NC</sub> = 100 mA, V <sub>COM</sub> = 0.9 V, 2.3 V			2.8	3.3		
Brain Gource On Tresistance	V+ = 0 V, INO/NC = 100 HIM, VCOM = 0.0 V, 2.0 V	Full			3.6	Ω	
On-Resistance Flatness	$V+ = 3 \text{ V}, I_{NO/NC} = 100 \text{ mA}, V_{COM} = 0 \text{ to } V+$	Room		0.24	1.1	3.2	
	VI = 0 V, INO/NC = 100 III/I, VCOM = 0 to VI	Full			1.3		
Switch Off Leakage Current	$V_{+} = 4.3 \text{ V}, V_{NO/NC} = 0.3 \text{ V/4 V}, V_{COM} = 4 \text{ V} / 0.3 \text{ V}$	Room	- 10	0.1	10		
Ownor on Leanage Carrent	V 1 = 4.5 V, V <sub>NO/NC</sub> = 0.5 V/4 V, V <sub>COM</sub> = 4 V / 0.5 V	Full	- 100		100	nA	
Channel On-Leakage Current	$V+ = 4.3 \text{ V}, V_{NO/NC} \text{ and } V_{COM} = 0.3 \text{ V} / 4 \text{ V}$	Room	- 10	0.1	10	- IIA	
Charmer on Leanage Carrent	V1 = 4.8 V, V <sub>NO/NC</sub> and V <sub>COM</sub> = 8.8 V / 4 V	Full	- 100		100		
Digital Control							
Input, High Voltage	V+ = 4.3 V	Full	1.6				
mpat, riigir voltage	V+ = 3 V		1.3			V	
Input, Low Voltage	V+ = 4.3 V	Full			0.6		
mput, 2011 Voltago	V+ = 3 V				0.5		
Input, Bias Current	$V_{IN} = V+$	Full	- 1	0.01	1	μΑ	
Dynamic Characteristics							
Turn On-Time	$V_{COM}$ or $V_{NO/NC} = 3$ V, $R_L = 50 \Omega$ , $C_L = 35$ pF	Room			90		
	COM S. THOING S.	Full			115		
Turn Off-Time	$V_{COM}$ or $V_{NO/NC} = 3$ V, $R_L = 50 \Omega$ , $C_L = 35$ pF	Room			70	ns	
	COM S. THOING S.	Full			85	-	
Break Before Make Time	$V_{COM}$ or $V_{NO/NC} = 3$ V, $R_L = 50 \Omega$ , $C_L = 35$ pF	Room	2				
Broak Boloro Make Time		Full	2				
Charge Injection	$C_L = 1 \text{ nF, } R_{GEN} = 0 \Omega$	Room		± 10		рC	
Off Isolation	$R_L = 50 \Omega, C_L = 5 pF, f = 1 MHz$			- 66			
Crosstalk	$R_L = 50 \ \Omega, \ C_L = 5 \ pF, \ f = 1 \ MHz$ Non-adjacent channels			- 110		dB	
3dB Bandwith	$C_L = 5 \text{ pF}, R_L = 50 \Omega$			186		MHz	
Source Off Capacitance	V <sub>IN</sub> = 0 or V+, f = 1 MHz			9			
Channel On Capacitance	V <sub>IN</sub> = 0 or V+, f = 1 MHz			26		pF	



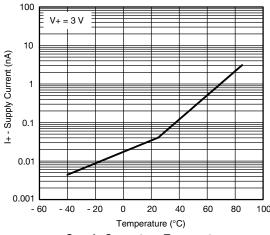
### TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C, unless otherwise noted)



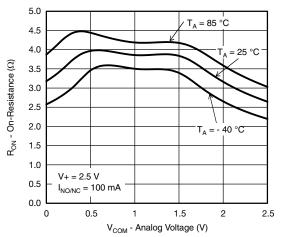
 $\rm R_{ON}$  vs.  $\rm V_{COM}$  and Single Supply Voltage



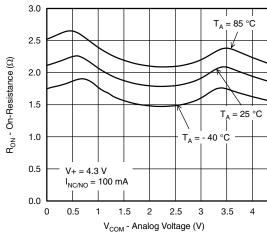
**R<sub>ON</sub> vs. Analog Voltage and Temperature** 



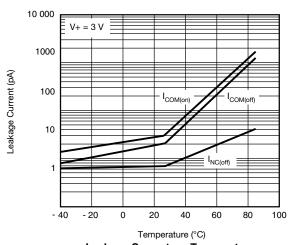
Supply Current vs. Temperature



R<sub>ON</sub> vs. Analog Voltage and Temperature

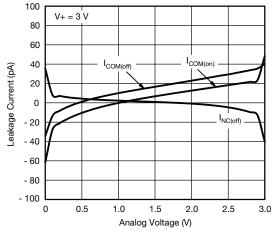


**R<sub>ON</sub> vs. Analog Voltage and Temperature** 

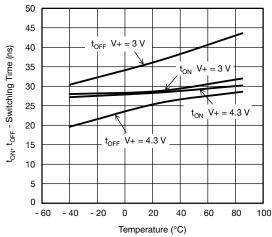


Leakage Current vs. Temperature

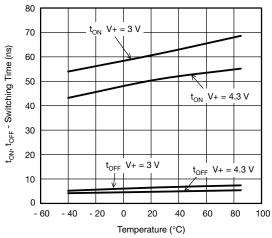
### **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



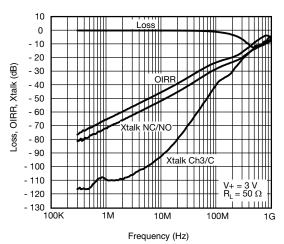
Leakage vs. Analog Voltage



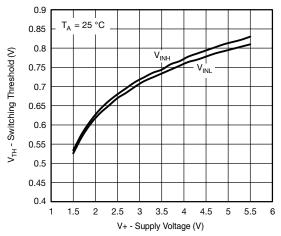
(NO) Switching Time vs. Temperature



(NC) Switching Time vs. Temperature

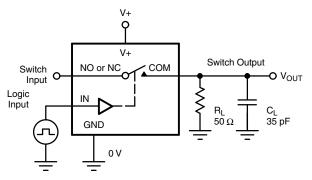


Insertion Loss, Off Isolation and Crosstalk



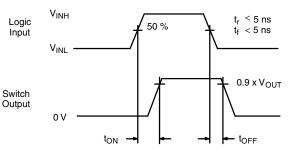
Switching Threshold vs. Supply Voltage

### **TEST CIRCUITS**



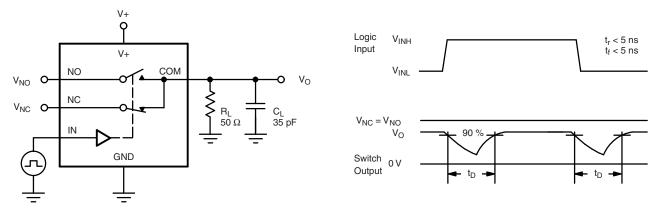
C<sub>L</sub> (includes fixture and stray capacitance)

$$V_{OUT} = V_{COM} \left( \frac{R_L}{R_L + R_{ON}} \right)$$



Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.

Figure 1. Switching Time



C<sub>L</sub> (includes fixture and stray capacitance)

Figure 2. Break-Before-Make Interval

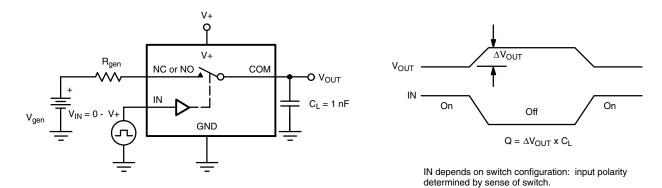


Figure 3. Charge Injection

### **TEST CIRCUITS**

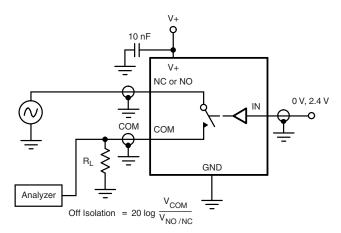


Figure 4. Off-Isolation

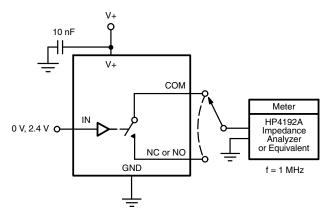


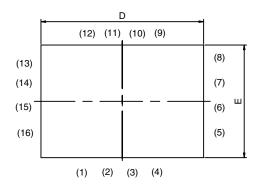
Figure 5. Channel Off/On Capacitance

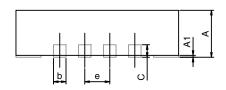
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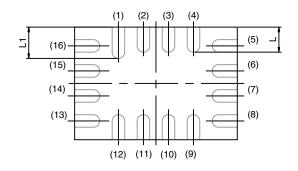




# miniQFN-16L







**BACK SIDE VIEW** 

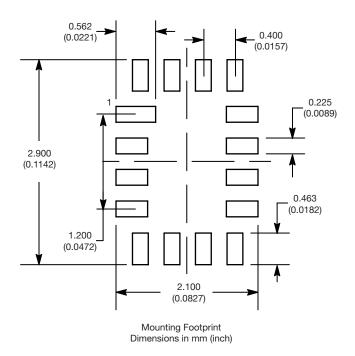
DIM	MILLIMETERS			INCHES			
	MIN.	NAM	MAX.	MIN.	NAM	MAX.	
А	0.70	0.75	0.80	0.0275	0.0295	0.0315	
A1	0	-	0.05	0	-	0.002	
b	0.15	0.20	0.25	0.0059	0.0078	0.0098	
С	0.15	0.20	0.25	0.0059	0.0078	0.0098	
D	2.50	2.60	2.70	0.0984	0.1023	0.1063	
Е	1.70	1.80	1.90	0.0669	0.0708	0.0748	
е	0.40 BSC				0.0157 BSC		
L	0.35	0.40	0.45	0.0137	0.0157	0.0177	
L1	0.45	0.50	0.55	0.0177	0.0196	0.0216	

ECN T16-0234-Rev. B, 09-May-16

DWG: 5954



### **RECOMMENDED MINIMUM PADS FOR MINI QFN 16L**





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